ABSTRACT OF THE DISCLOSURE

A scanning optical system using a shortwavelength light of 500 nm or less uses a reflecting mirror having a higher absolute reflectivity and having reduced wavelength and angle dependences. Divergent ray of light emitted from a semiconductor laser is converted into an approximately parallel light beam by a collimator lens and the diameter of the light flux is reduced by an aperture before travel to a polygon mirror. 10 The light beam from the polygon mirror passes through scanning lenses to form a small spot at any point in the entire scanning area. The semiconductor laser is a gallium nitride 15 semiconductor laser having an oscillation wavelength of 408 nm. The polygon mirror has such a characteristic that, if the complex refractive index N of a metallic film contributing to a reflection characteristic of the reflecting mirror is defined as $N(\lambda) = n(\lambda) - ik(\lambda)$, then $k(\lambda) >$ 20 $\sqrt{(-n(\lambda)^2 + 18n(\lambda) - 1)}$ is satisfied.